Product specification

BT137 series

GENERAL DESCRIPTION

Glass passivated triacs in a plastic envelope, intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

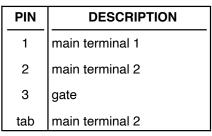
PINNING - TO220AB

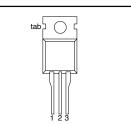
QUICK REFERENCE DATA

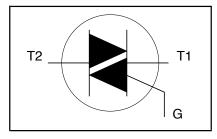
SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
	BT137- BT137- BT137- BT137-	500 500F 500G	600 600F 600G	800 800F 800G	
V _{DRM}	Repetitive peak off-state	500	600	800	V
I _{T(RMS)} I _{TSM}	voltages RMS on-state current Non-repetitive peak on-state current	8 65	8 65	8 65	A A

PIN CONFIGURATION

SYMBOL







LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{DRM}	Repetitive peak off-state voltages		-	-500 500 ¹	-600 600 ¹	-800 800	v
T _(RMS)	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 102 \degree C$ full sine wave; $T_j = 25 \degree C$ prior to surge	-		8		A
		t = 20 ms	-		65		A
l ² t	l ² t for fusing	t = 16.7 ms	-		71		A A ² s
dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after	I = 10 ms $I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_C/dt = 0.2 \text{ A/us}$	-		21		AS
	triggering	T2+G+	-		50		A/μs
		T2+ G-	-		50		A/μs
		T2- G-	-		50		A/µs
	Book goto ourront	T2- G+	-		10 2		A/μs
I _{GM} V	Peak gate current Peak gate voltage				2 5		
	Peak gate power				5 5		Ŵ
$\begin{array}{c} P_{G(AV)}\\ P_{G(AV)}\\ T_{stg}\\ T_{j} \end{array}$	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125		ů Č Č

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 $A/\mu s$.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air	- -	- - 60	2.0 2.4 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.		UNIT	
	Gate trigger current	BT137- V _D = 12 V; I _T = 0.1 A				F	G	
I _{GT}		T2+ G+	-	5	35	25	50	mA
		T2+ G- T2- G-	-	8 11	35 35	25 25	50 50	mA mA
 IL	Latching current	T_2-G_+ V _D = 12 V; I _{GT} = 0.1 A	-	30	70	70	100	mA
<u>''</u>		T2+G+	-	7	30	30	45	mA
		T2+ G- T2- G-	-	16 5	45 30	45 30	60 45	mA mA
I _H	Holding current	T2- G+ V _D = 12 V; I _{GT} = 0.1 A	-	7 5	45 20	45 20	60 40	mA mA
V _T V _{GT}	On-state voltage Gate trigger voltage	$I_{T} = 10 \text{ A}$ $V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$	-	1.3 0.7		1.65 1.5		V V
I _D	Off-state leakage current		0.25 -	0.4 0.1		- 0.5		V mA

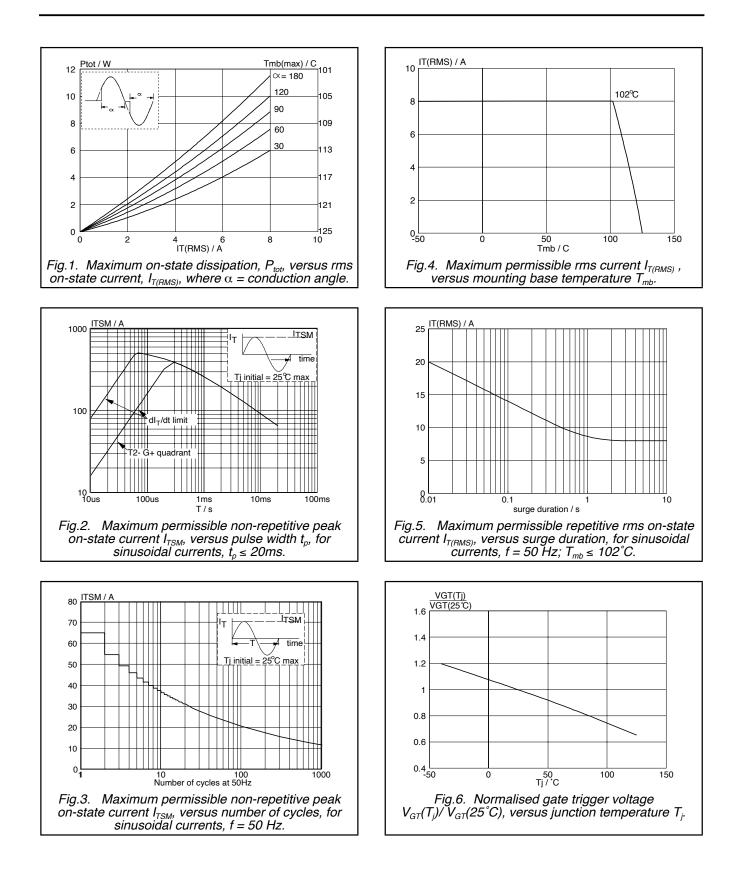
DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

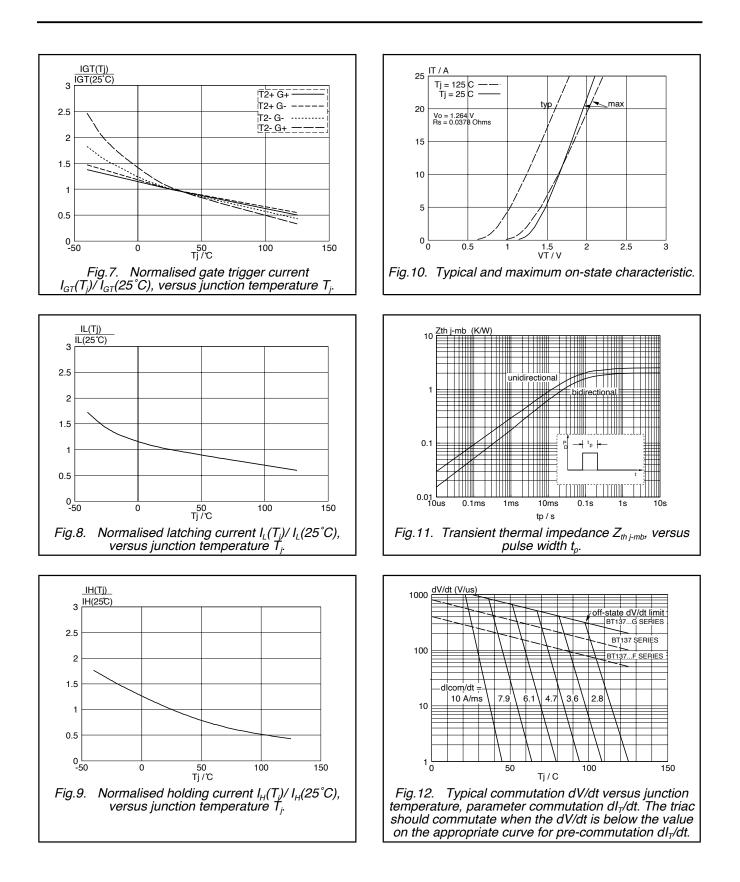
SYMBOL	PARAMETER	CONDITIONS		MIN.		TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	BT137- $V_{DM} = 67\% V_{DRM(max)};$ $T_i = 125 °C; exponential$	 100	F 50	G 200	250	-	V/μs
dV _{com} /dt	Critical rate of change of commutating voltage	waveform; gate open circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 95 ^{\circ}\text{C};$ $I_{T(RMS)} = 8 \text{ A};$ $dI_{com}/dt = 3.6 \text{ A/ms}; gate$	-	-	10	20	-	V/µs
t _{gt}	Gate controlled turn-on time	open circuit $I_{TM} = 12 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A}; dI_G/dt = 5 \text{ A}/\mu \text{s}$	-	-	-	2	-	μs

Product specification

BT137 series

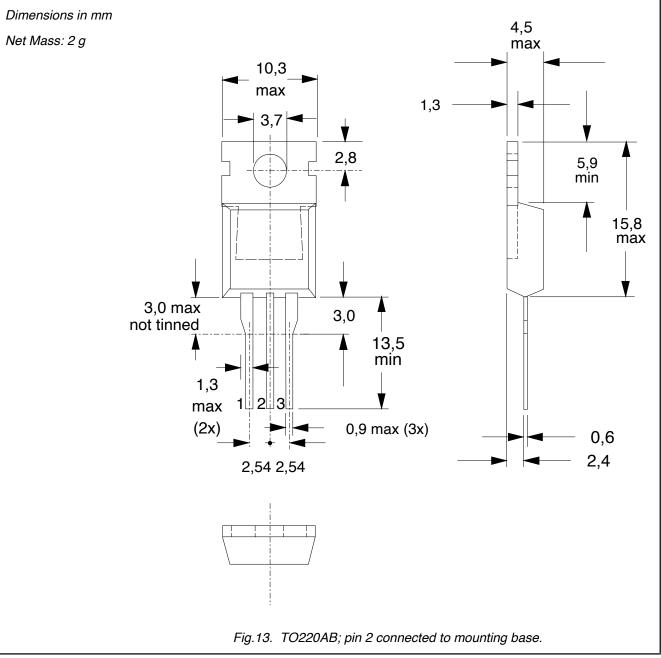


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MECHANICAL DATA



Notes
1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status						
Objective specification	Dbjective specification This data sheet contains target or goal specifications for product development.					
Preliminary specification	reliminary specification This data sheet contains preliminary data; supplementary data may be published late					
Product specification	This data sheet contains final product specifications.					
Limiting values						
or more of the limiting val operation of the device a	in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one lues may cause permanent damage to the device. These are stress ratings only and t these or at any other conditions above those given in the Characteristics sections of applied. Exposure to limiting values for extended periods may affect device reliability.					
Application information						
Where application information is given, it is advisory and does not form part of the specification.						
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